## Amendments to the Claims ar as follows:

(Currently Amended) A thin-film capacitor element comprising:

 an insulative substrate having a via hole filled with a conductive material;

a lower electrode;

a dielectric layer; and

an upper electrode; wherein the lower electrode, the dielectric layer, and the upper electrode are successively deposited in order on the insulative substrate, wherein

either one of the lower electrode and the upper electrode connects to <u>anthe</u> end face of the conductive material; and the dielectric layer is shaped like a ring to surround the via hole.

- (Currently Amended) A thin-film capacitor element according to
   Claim 1, wherein the dielectric layer is shaped like a ring with the via hole as <a href="mailto:athe-enter.">athe</a> center.
- 3. (Original) A thin-film capacitor element according to Claim 1, wherein the insulative substrate is made of low-temperature-sintered ceramic.